



# THE DATASHEET OF HMC802LP3ETR



### Typical Applications

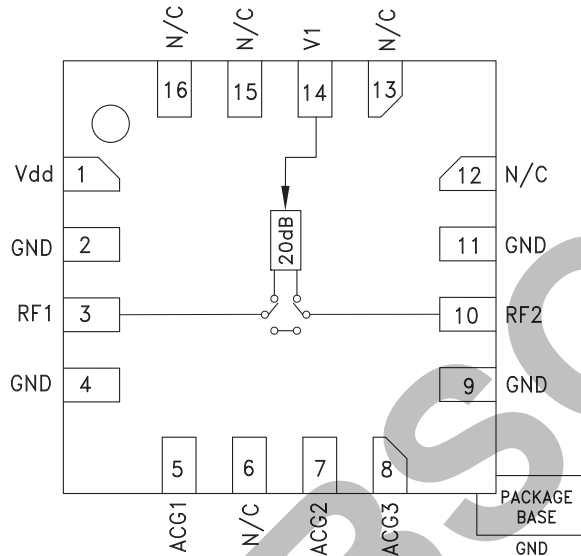
The HMC802LP3E is ideal for both RF and IF applications:

- Test Equipment and Sensors
- ISM, MMDS, WLAN, WiMAX, WiBro
- Microwave Radio & VSAT
- Cellular Infrastructure

### Features

- ± 0.6 dB Typical Step Error
- Low Insertion Loss: 3 dB
- High IP3: +55 dBm
- Single Control Line
- TTL/CMOS Compatible Control
- Single +5V Supply
- 16 Lead 3x3mm SMT Package: 9mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC802LP3E is a broadband bidirectional 1-bit GaAs IC digital attenuator in a low cost leadless surface mount package. This single positive control line digital attenuator utilizes off chip AC ground capacitors for near DC operation, making it suitable for a wide variety of RF and IF applications. Covering DC to 10 GHz, the insertion loss is less than 3 dB typical and attenuation accuracy is excellent at ±0.6 dB typical. The attenuator also features a high IIP3 of +55 dBm. One TTL/CMOS control input is used to select the attenuation state and a single Vdd bias of +5V is required.

### Electrical Specifications, $T_A = +25^\circ C$ , With $V_{dd} = +5V$ & $V_{ctl} = 0/+5V$

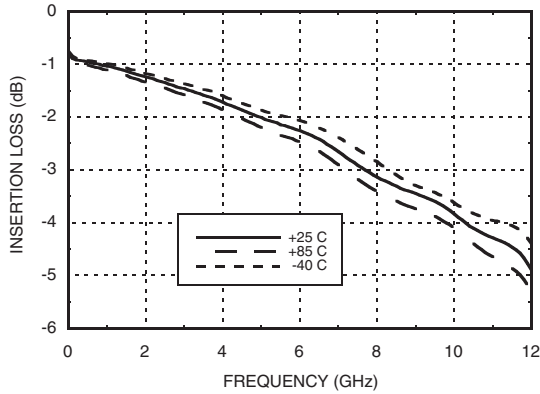
Parameter	Frequency (GHz)	Min.	Typ.	Max.	Units
Insertion Loss	DC - 4 GHz		1.5	2.5	dB
	4 - 8 GHz		3.0	4.0	dB
	8 - 10 GHz		3.5	4.5	dB
Attenuation Range	DC - 10 GHz		20		dB
Return Loss (RF1 & RF2, Both States)	DC - 6 GHz		18		dB
	6 - 10 GHz		12		dB
Attenuation Accuracy: (Referenced to Insertion Loss)	DC - 8 GHz		± 0.4	± 0.6	dB
	8 - 10 GHz		± 0.8	± 1.2	dB
Input Power for 0.1 dB Compression	DC - 0.4 GHz		20		dBm
	0.4 - 10 GHz		30*		dBm
Input Third Order Intercept Point (Two-Tone Input Power= 0 dBm Each Tone)	DC - 0.4 GHz		45		dBm
	0.4 - 10 GHz		55		dBm
Switching Characteristics	DC - 10 GHz				
		tRISE, tFALL (10/90% RF)		120	ns
		tON, tOFF (50% CTL to 10/90% RF)		150	ns

\* For frequencies greater than 0.4 GHz, the 0.1 dB compression point is greater than the absolute maximum RF input power of 30 dBm.

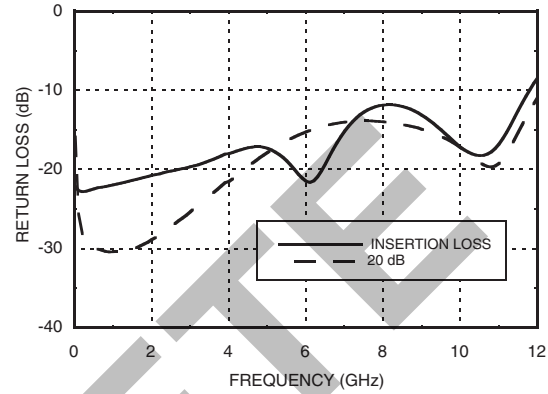


## 20 dB GaAs MMIC 1-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 10 GHz

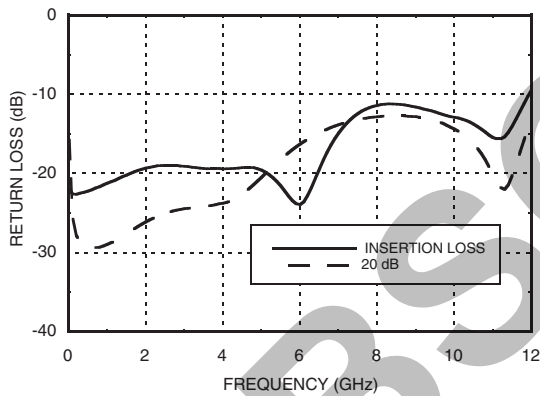
**Insertion Loss**



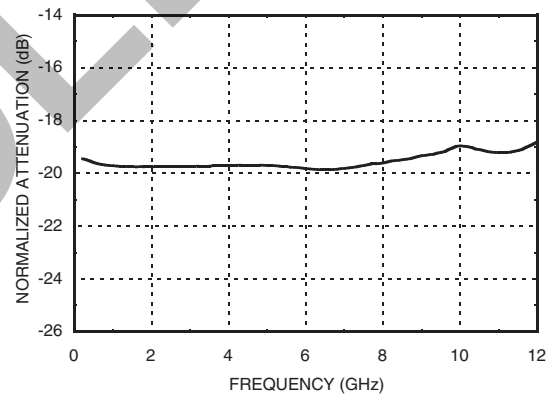
**Input Return Loss**



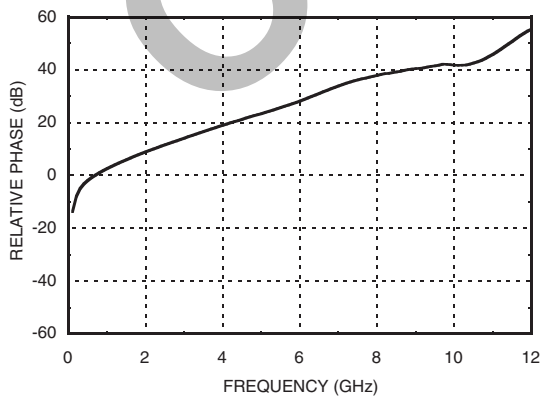
**Output Return Loss**



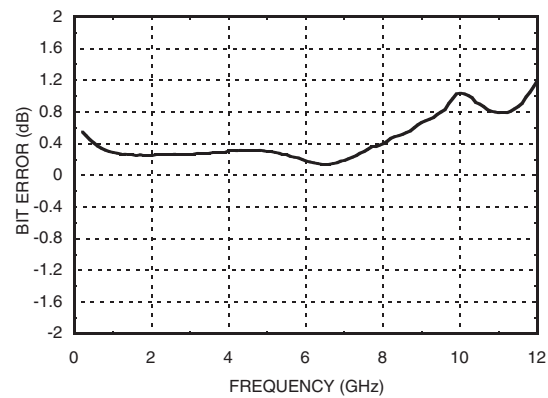
**Relative Attenuation**



**Relative Phase vs. Frequency**



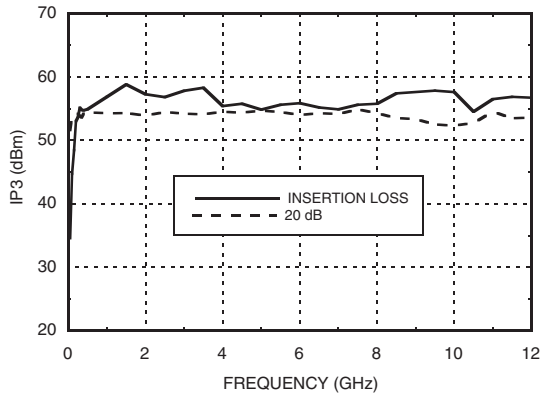
**Bit Error vs. Frequency**



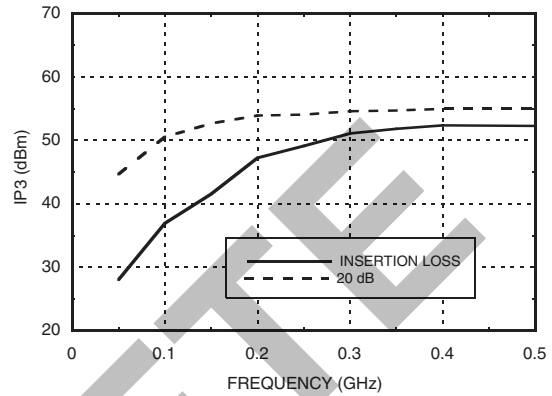


## 20 dB GaAs MMIC 1-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 10 GHz

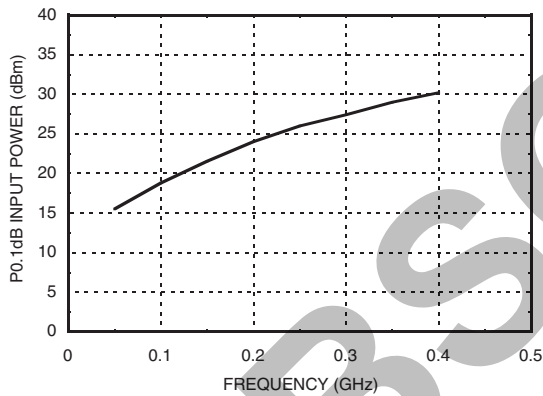
### Input IP3 vs. Frequency



### Input IP3 vs. Frequency (Low Frequency Detail)



### Input Power for 0.1 dB Compression\* (Low Frequency Detail)



### Truth Table

Control Voltage Input	Attenuation State
V1	RF1 - RF2
High	Reference Insertion Loss
Low	20 dB

### Bias Voltage & Current

Vdd = +5 Vdc ± 10%	
Vdd (Vdc)	Idd (Typ.) (mA)
4.5	0.21
5.0	0.23
5.5	0.25

### Control Voltage

State	Bias Condition
Low	0 to +0.8V @ -1 μA Typ.
High	+2 to +5V @ 30 μA Typ.

Note: Vdd = +5V

\* For frequencies greater than 0.4 GHz, the 0.1 dB compression point is greater than the absolute maximum RF input power of 30 dBm.



## 20 dB GaAs MMIC 1-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 10 GHz

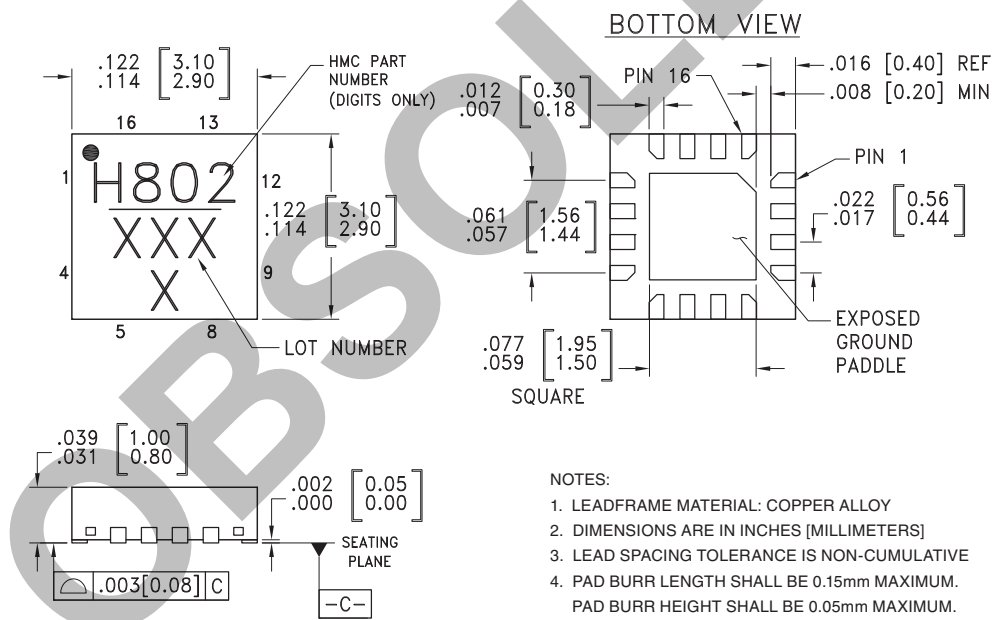
### Absolute Maximum Ratings

RF Input Power (DC - 10 GHz)	+30 dBm
Control Voltage Range (V1)	-1 to Vdd + 1V
Bias Voltage (Vdd)	+7 Vdc
Channel Temperature	150 °C
Continuous P <sub>diss</sub> (T = 85 °C) (derate 12 mW/°C above 85 °C)	0.783 W
Thermal Resistance (channel to ground paddle)	83 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



### Package Information


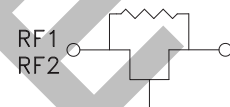
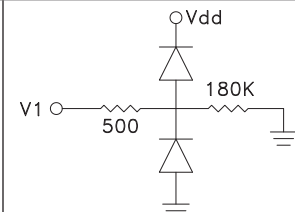
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC802LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[1]</sup>	H802 XXXX

[1] Max peak reflow temperature of 260 °C

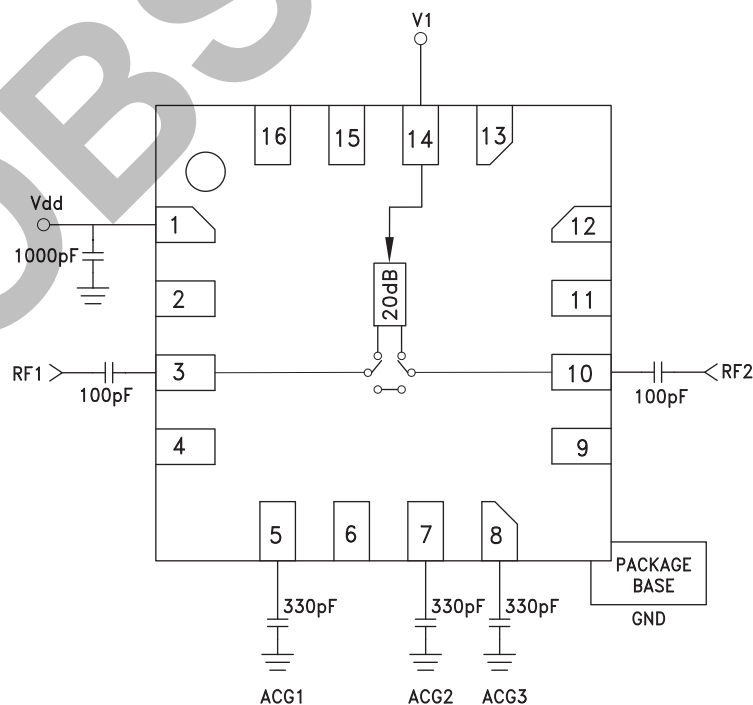
[2] 4-Digit lot number XXXX

## 20 dB GaAs MMIC 1-BIT DIGITAL POSITIVE CONTROL ATTENUATOR, DC - 10 GHz

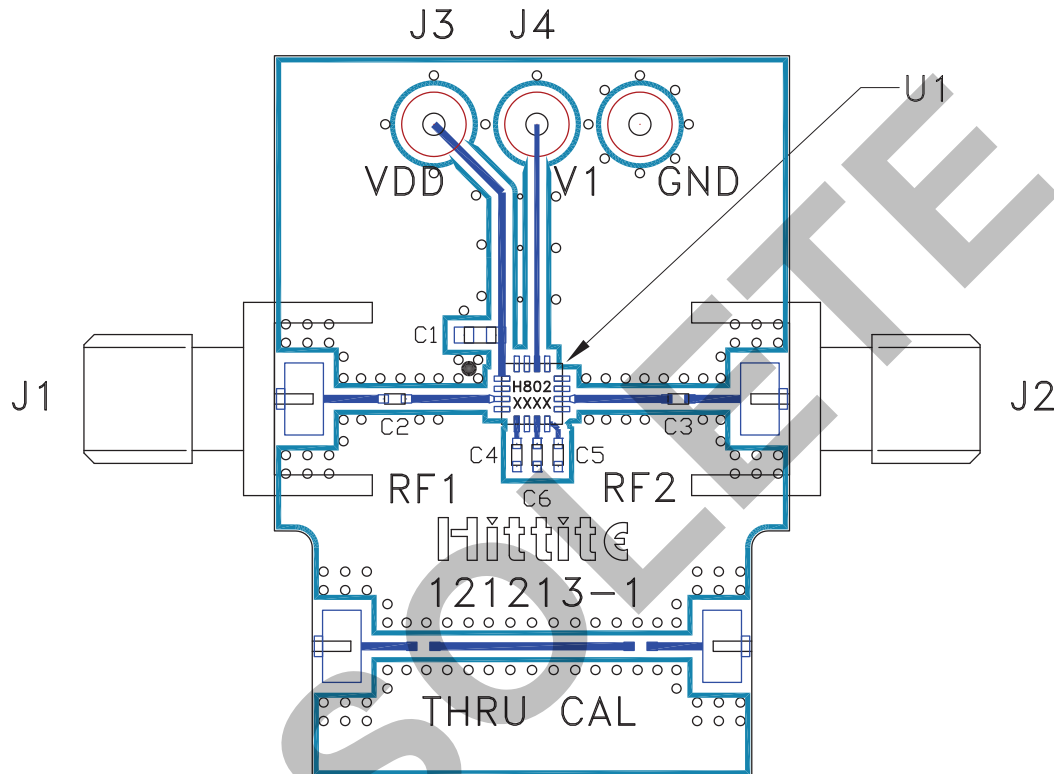
### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vdd	Supply Voltage.	
2, 4, 9, 11	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
3, 10	RF1, RF2	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required. Select value based on lowest frequency of operation.	
5, 7, 8	ACG1, ACG2, ACG3	External capacitor to ground is required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible.	
6, 12, 13, 15, 16	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
14	V1	See truth table and control voltage table.	

### Application Circuit



### Evaluation PCB



### List of Materials for Evaluation PCB 127103 [1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Connector
C1	1000 pF Capacitor, 0603 Pkg.
C2, C3	100 pF Capacitor, 0402 Pkg.
C4 - C6	330 pF Capacitor, 0402 Pkg.
U1	HMC802LP3E Digital Attenuator
PCB [2]	121213 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- ⊖ [View HMC802LP3ETR on WIN SOURCE](#)
- ⊖ [Analog Devices Inc. Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

- ✓ Global Sourcing Solution
- ✓ Obsolete Management
- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management